Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-496-6920

Inclosure Material:
Metal
Overall Length:
0.210 inches
Terminal Length:
0.250 inches
Overall Diameter:
0.230 inches
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-18
Electrode Internally-electrically Connected To Case:
Gate
Mounting Method:
Terminal
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
30.0 reverse voltage, instantaneous
Current Rating Per Characteristic:
5.00 milliamperes zero-gate-voltage source current horsepower metric and 1.50 milliamperes drain current peak
Power Rating Per Characteristic:
300.0 milliwatts any acceptable horsepower metric
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius ambient air
Terminal Type And Quantity:
3 uninsulated wire lead
Specification Data:
80131-release5472 professional/industrial association specification
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0